

Description

The AON6407 uses advanced trench technology

to provide excellent $\mathsf{R}_{\mathsf{DS}(\mathsf{ON})}$, low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

General Features

V_{DS} = -30V I_D =-100A

 $R_{DS(ON)} < 4 \text{ m}\Omega \text{ V}_{GS}$ =-10V

Application

Battery protection

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

| SSS G DD DD |
|-------------------|
| Pin 1 |

DFN5X6-8L (PDFN-8(5.8x4.9))



P-Channel MOSFET

| Product ID | Pack | Brand | Qty(PCS) |
|------------|-----------------------------|------------|----------|
| AON6407 | DFN5X6-8L(PDFN-8(5.8x4x.9)) | HXY MOSFET | 5000 |

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Units | |
|-------------|--|------------|-------|--|
| Vds | Drain-Source Voltage | -30 | V | |
| Vgs | Gate-Source Voltage | ±20 | V | |
| I₀@Tc=25°C | Continuous Drain Current, V _{GS} @ 10V ¹ | -100 | А | |
| l⊳@Tc=100°C | Continuous Drain Current, V _{GS} @ 10V ¹ | -70 | А | |
| Ідм | Pulsed Drain Current ² | -250 | А | |
| EAS | Single Pulse Avalanche Energy ³ | 80 | mJ | |
| las | Avalanche Current | -70 | А | |
| P₀@Tc=25°C | Total Power Dissipation ⁴ | 120 | W | |
| Тѕтс | Storage Temperature Range | -55 to 150 | °C | |
| TJ | Operating Junction Temperature Range | -55 to 150 | °C | |
| Reja | Thermal Resistance Junction-Ambient ¹ | 50 | °C/W | |
| Rejc | Thermal Resistance Junction-Case ¹ | 1.6 | °C/W | |



Electrical Characteristics (TJ=25 °C, unless otherwise noted)

| Symbol | Parameter Conditions | | Min. | Тур. | Max. | Unit | |
|---------------------|--|--|------|------|------|------|--|
| BV_{DSS} | Drain-Source Breakdown Voltage | rce Breakdown Voltage V _{GS} =0V , I _D =-250uA | | | | V | |
| R _{DS(ON)} | Static Drain-Source On-Resistance ² | V _{GS} =-10V , I _D =-20A | | 3 | 4.0 | mΩ | |
| | Static Drain-Source On-Resistance | V _{GS} =-4.5V , I _D =-15A | | 4.2 | 6.0 | mΩ | |
| V _{GS(th)} | Gate Threshold Voltage | Gate Threshold Voltage $V_{GS}=V_{DS}$, $I_D=-250uA$ | | | -2.5 | V | |
| | | V _{DS} =-24V , V _{GS} =0V , T _J =25℃ | | | -1 | | |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =-24V , V _{GS} =0V , TJ=55℃ | | | -5 | uA | |
| I _{GSS} | Gate-Source Leakage Current | $V_{GS}=\pm 20V$, $V_{DS}=0V$ | | | ±100 | nA | |
| Rg | Gate Resistance | V _{DS} =0V , V _{GS} =0V , f=1MHz | | 1.2 | | Ω | |
| Qg | Total Gate Charge (-10V) | | | 60 | | | |
| Q_gs | Gate-Source Charge | V _{DS} =-15V , V _{GS} =-10V , I _D =-18A | | 9 | | nC | |
| Q_{gd} | Gate-Drain Charge | | | 15 | | | |
| T _{d(on)} | Turn-On Delay Time | | | 17 | | | |
| Tr | Rise Time | V_{DD} =-15V , V_{GS} =-10V , R_{G} =3.3 Ω , | | 40 | | | |
| T _{d(off)} | Turn-Off Delay Time | I _D =-20A | | 55 | | ns | |
| T _f | Fall Time | | | 13 | | | |
| C _{iss} | Input Capacitance | | | 3450 | | | |
| C _{oss} | Output Capacitance | V _{DS} =-25V , V _{GS} =0V , f=1MHz | | 255 | | pF | |
| C _{rss} | Reverse Transfer Capacitance | | | 140 | | | |
| ls | Continuous Source Current ^{1,5} | $V_G = V_D = 0V$, Force Current | | | -100 | А | |
| V_{SD} | Diode Forward Voltage ² | V_{GS} =0V , I_{S} =-1A , T_{J} =25°C | | | -1.2 | V | |
| t _{rr} | Reverse Recovery Time | IF=-20A , di/dt=100A/µs , | | 22 | | nS | |
| Q _{rr} | Reverse Recovery Charge | | | 72 | | nC | |

Note :

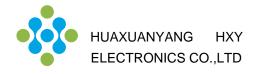
1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

2.The data tested by pulsed , pulse width $\leq 300 \text{us}$, duty cycle $\leq 2\%$

3.The EAS data shows Max. rating . The test condition is V_{DD}=-50V,V_{GS}=-10V,L=0.1mH,I_{AS}=-40A 4.The power dissipation is limited by 150°C junction temperature

5. The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation

6.The maximum current rating is package limited.



Typical Characteristics

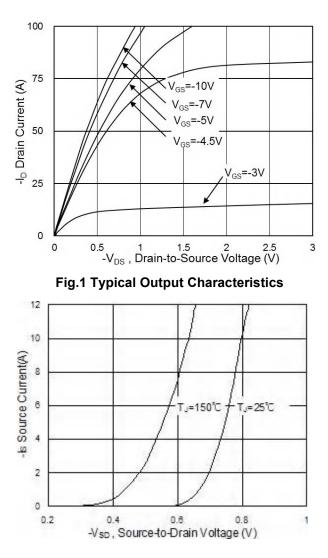
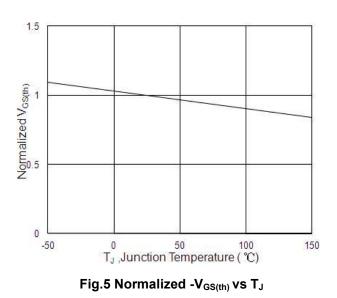
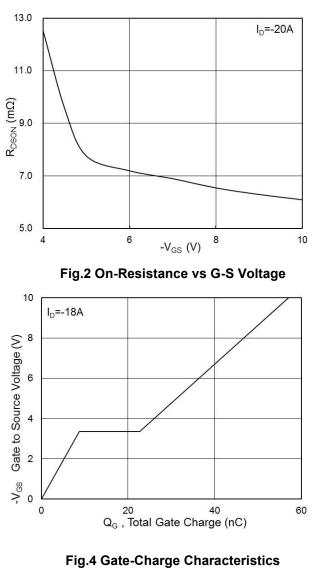
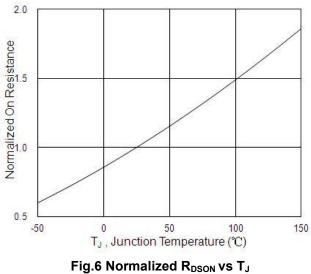
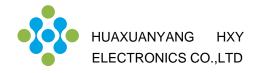


Fig.3 Source Drain Forward Characteristics









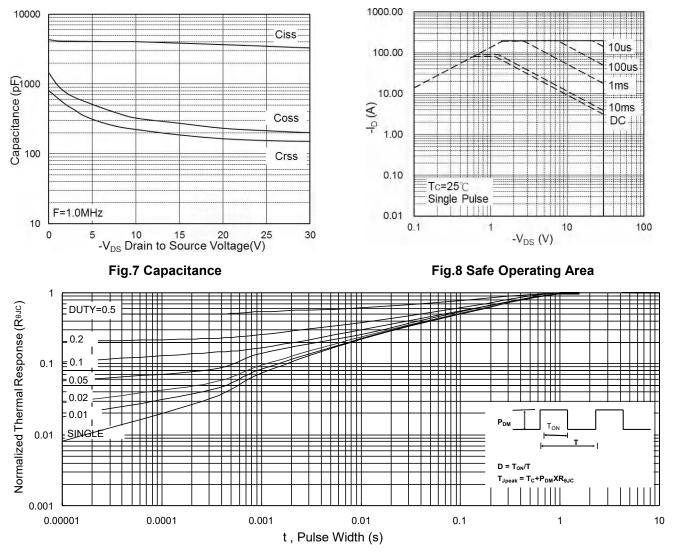


Fig.9 Normalized Maximum Transient Thermal Impedance

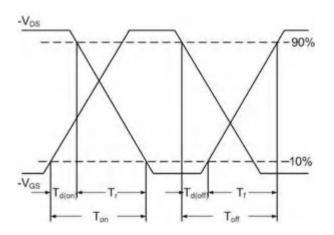


Fig.10 Switching Time Waveform

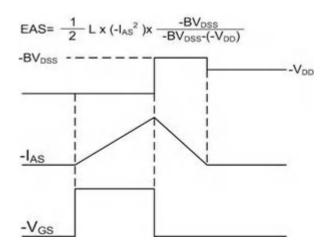
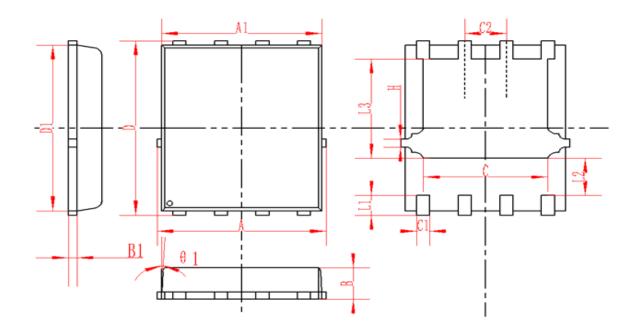


Fig.11 Unclamped Inductive Switching Waveform



DFN5X6-8L(PDFN-8(5.8x4.9)) Package Information



| SYMBOL | | MM | | | INCH | | |
|----------|----------|------|-------|------------------|-------|-------|--|
| STIVIDOL | MIN | NOM | MAX | MIN | NOM | MAX | |
| А | 4.95 | 5 | 5.05 | 0.195 | 0.197 | 0.199 | |
| A1 | 4.82 | 4.9 | 4.98 | 0.190 | 0.193 | 0.196 | |
| D | 5.98 | 6 | 6.02 | 0.235 | 0.236 | 0.237 | |
| D1 | 5.67 | 5.75 | 5.83 | 0.223 | 0.226 | 0.230 | |
| В | 0.9 | 0.95 | 1 | 0.035 | 0.037 | 0.039 | |
| B1 | 0.254REF | | | 0.010REF | | | |
| С | 3.95 | 4 | 4.05 | 0.156 | 0.157 | 0.159 | |
| C1 | 0.35 | 0.4 | 0.45 | 0.014 | 0.016 | 0.018 | |
| C2 | 1.27TYP | | | 2 1.27TYP 0.5TYP | | | |
| θ1 | 8° | 10° | 12° | 8° | 10° | 12° | |
| L1 | 0.63 | 0.64 | 0.65 | 0.025 | 0.025 | 0.026 | |
| L2 | 1.2 | 1.3 | 1.4 | 0.047 | 0.051 | 0.055 | |
| L3 | 3.415 | 3.42 | 3.425 | 0.134 | 0.135 | 0.135 | |
| Н | 0.24 | 0.25 | 0.26 | 0.009 | 0.010 | 0.010 | |



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